

Single-Output LDO Regulators

35V Voltage Resistance 1A LDO Regulators

BDxxC0A-C series BDxxC0AW-C series

General Description

The BDxxC0A-C series and the BDxxC0AW-C series are low-saturation regulators. This series feature variable and fixed voltage output with selectable Shutdown switch (referred to as SW); Vout-3.3V, 5.0V, 8.0V and 9.0V.Five conventional PKGs; TO252-3/5, HRP5 and TO263-3(F)/5 are available. This series has a built-in over-current protection circuit that prevents the destruction of the IC due to output short circuits and a thermal Shutdown circuit that protects the IC from thermal damage due to overloading.

Features

- 1) Output current capability: 1A
- 2) Output voltage: Variable, 3.3V, 5.0V, 8.0V and 9.0V
- 3) High output voltage accuracy (Ta=25°C, TO252-3/5, HRP5): ±1%
- 4) Low saturation with PDMOS output
- 5) Built-in over-current protection circuit that prevents the destruction of the IC due to output short circuits
- Built-in thermal Shutdown circuit for protecting the IC from thermal damage due to overloading
- 7) Low ESR Capacitor
- 8) TO252-3/5, HRP5, TO263-3(F)/5 package
- 9) AEC-Q100 Qualified (Note 1) (Note 1: Grade 1)

Key Specifications

Supply Voltage(Vo ≥ 3.0V): Vo+1.0V to 26.5V
 Supply Voltage(Vo < 3.0V): 4.0V to 26.5V
 Output Voltage(BD00C0AW): 1.0V to 15.0V
 Output Current: 1A

Output Voltage Precision

(Ta=25°C): $\pm 1\%$ (TO252-3/5, HRP5) (-40°C \leq Ta \leq +125°C): $\pm 3\%$

• Operating Temperature Range: -40°C ≤ Ta ≤ +125°C

Packages W(Typ) x D(Typ) x H(Max)

TO252-5 6.50mm x 9.50mm x 2.50mm



TO252-3 6.50mm x 9.50mm x 2.50mm



HRP5 9.395mm x 10.540mm x 2.005mm



TO263-5 10.16mm x 15.10mm x 4.70mm



TO263-3(F) 10.16mm x 15.10mm x 4.70mm

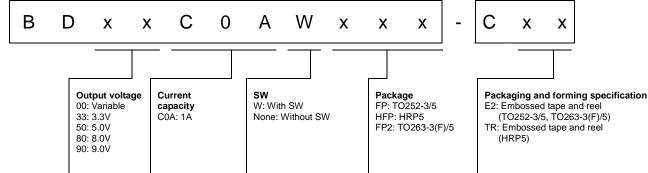


Applications

Automotive

(body, audio system, navigation system, etc.)

Ordering part number



OProduct structure: Silicon monolithic integrated circuit OThis product is not designed protection against radioactive rays.

Lineup

Articles	Variable	3.3	5.0	8.0	9.0	Package	
BDxxC0AWFP-CE2	0	0	0	0	0	TO252-5	Reel of 2000
BDxxC0AFP-CE2	_	0	0	0	0	TO252-3	Reel of 2000
BDxxC0AWHFP-CTR	0	0	0	0	0	HRP5	Reel of 2000
BDxxC0AHFP-CTR	-	0	0	0	0	HRP5	Reel of 2000
BDxxC0AWFP2-CE2	0	0	0	0	0	TO263-5	Reel of 500
BDxxC0AFP2-CE2	-	0	0	0	0	TO263-3(F)	Reel of 500

Typical Application Circuits

⟨Output Voltage Variable Type (With SW)⟩

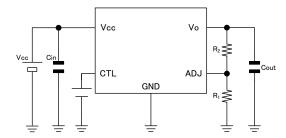


Figure 1. Typical Application Circuit Output Voltage Variable Type (With SW)

(Output Voltage Fixation Type (With SW))

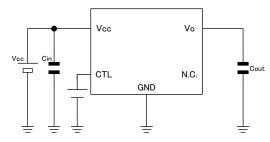


Figure 2. Typical Application Circuit Output Voltage Fixation Type (With SW)

⟨Output Voltage Fixation Type (Without SW)⟩

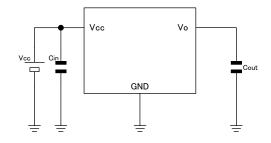
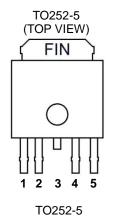
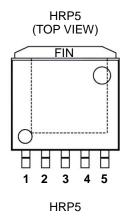


Figure 3. Typical Application Circuit Output Voltage Fixation Type (Without SW)

Pin Configurations/Pin Descriptions

(With SW (TO252-5/HRP5/TO263-5))





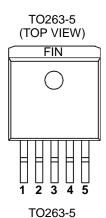
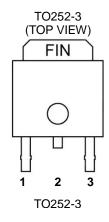


Figure 4. Pin Configurations (With SW)

Pin No.	Pin Name	Function		
1	CTL Output Control Pin			
2	Vcc	Power Supply Pin		
3	N.C. (Note 1) GND	N.C. Pin (TO252-5) GND (HRP5/TO263-5)		
4	Vo	Output Pin		
5	ADJ N.C. ^(Note 1)	Variable Pin (BD00C0AW) N.C. Pin (BD33/50/80/90C0AW)		
FIN	GND	GND		

(Note 1) N.C.Pin can be open. Because it isn't connect it inside of IC.

⟨Without SW (TO252-3/TO263-3(F))⟩



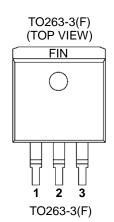


Figure 5. Pin Descriptions (Without SW)

Pin No.	Pin Name	Function
1	Vcc	Power Supply Pin
2	N.C. (Note 1) GND	N.C. Pin (TO252-3) GND (TO263-3(F))
3	Vo	Output Pin
FIN	GND	GND

(Note 1) N.C.Pin can be open. Because it isn't connect it inside of IC.

⟨Without SW (HRP5)⟩

HRP5 (TOP VIEW)

FIN

1 2 3 4 5

Figure 6. Pin Descriptions (Without SW) (HRP5)

HRP5

Pin No.	Pin Name	Function			
1	Vcc	Power Supply Pin			
2	N.C. (Note 1)	N.C. Pin			
3	GND	GND			
4	N.C.	N.C. Pin			
5	Vo	Output Pin			
FIN	GND	GND			

(Note 1) N.C.Pin can be open. Because it isn't connect it inside of IC.

Block Diagrams

⟨BD00C0AWFP/WHFP/WFP2-C (Output Voltage Variable Type, With SW) ⟩

■TO252-5/HRP5/TO263-5

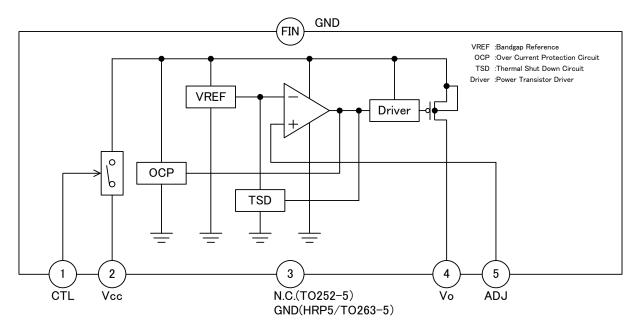


Figure 7. Block diagram BD00C0AWFP/WHFP/WFP2-C (Output Voltage Variable Type, With SW)

⟨BDxxC0AWFP/WHFP/WFP2-C (Output Voltage Fixation Type, With SW) ⟩

■TO252-5/HRP5/TO263-5

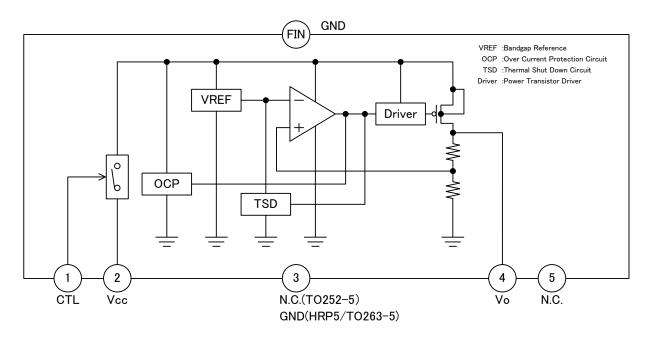


Figure 8. Block diagram BDxxC0AWFP/WHFP/WFP2-C (Output Voltage Fixation Type, With SW)

⟨BDxxC0AFP/HFP/FP2-C (Output Voltage Fixation Type, Without SW) ⟩

■TO252-3/TO263-3(F)

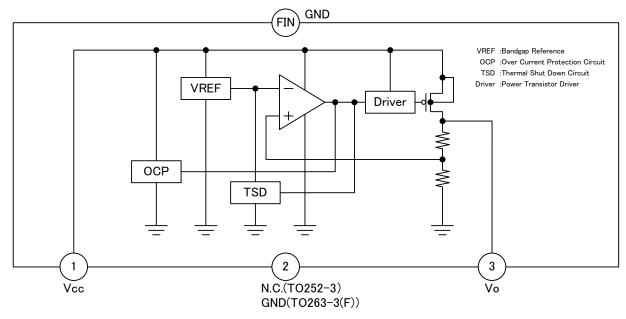


Figure 9. Block diagram BDxxC0AFP/FP2-C (Output Voltage Fixation Type, Without SW)

■HRP5

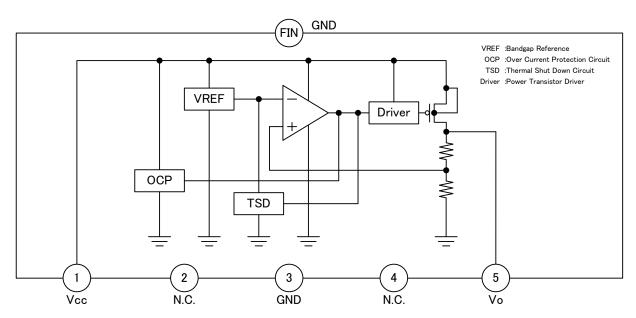


Figure 10. Block diagram
BDxxC0AHFP-C (Output Voltage Fixation Type, Without SW)

Absolute Maximum Ratings (Ta= 25°C)

Parameter	Symbol	Ratings	Unit
Supply Voltage (Note 1)	Vcc	-0.3 to +35.0	V
Output Control Voltage (With SW) (Note 2)	Vctl	-0.3 to +35.0	V
Operating Temperature Range	Topr	-40 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C
Maximum Junction Temperature	Tjmax	150	°C

(Note 1) Do not exceed Pd (Please refer to Power Dissipation in P.27-29).
(Note 2) The order of starting up power supply (Vcc) and CTL pin doesn't have either in the problem within the range of the operation power-supply voltage ahead.

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Recommended Operating Conditions (-40°C ≤ Ta ≤ +125°C)

Parameter	Symbol	Min	Max.	Unit
Supply Voltage (Vo≥3.0V)	Vcc	Vo+1	26.5	V
Supply Voltage (Vo < 3.0V)	Vcc	4.0	26.5	V
Startup Voltage (Io=0mA)	Vcc	-	3.8	V
Output Control Voltage (With SW)	V _{CTL}	0	26.5	V
Output Current	lo	0	1.0	Α
Output Voltage (BD00C0AW) (Note 1)	Vo	1.0	15.0	V

(Note 1) Please refer to Notes15 for use when you use BD00C0AW by output voltage 1.0V ≤ Vo < 3.0V.

Thermal Resistance (Note 1)

Development	0	Thermal Res	1.1:4	
Parameter	Symbol	1s ^(Note 3)	2s2p ^(Note 4)	Unit
TO252-3, TO252-5				
Junction to Ambient	θја	136	23	°C/W
Junction to Top Characterization Parameter ^(Note 2)	Ψ_{JT}	17	3	°C/W
HRP5				
Junction to Ambient	θја	120	22	°C/W
Junction to Top Characterization Parameter ^(Note 2)	Ψ_{JT}	8	3	°C/W
TO263-3(F), TO263-5				
Junction to Ambient	θЈΑ	81	21	°C/W
Junction to Top Characterization Parameter ^(Note 2)	Ψлτ	8	2	°C/W

(Note 1)Based on JESD51-2A (Still-Air)

(Note 2)The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package.

(Note 3)Using a	PCB	board	based	on	JESD51	-3.

Layer Number of Measurement Board	Material	Board Size
Single	FR-4	114.3mm x 76.2mm x 1.57mmt
Тор		
Copper Pattern	Thickness	
Footprints and Traces	70µm	

(Note 4)Using a PCB board based on JESD51-5, 7.

Layer Number of	Material	Board Size		Thermal Vi	a ^(Note 5)
Measurement Board	Material	Dodiu Size		Pitch	Diameter
4 Layers	FR-4	114.3mm x 76.2mm x	x 1.6mmt	1.20mm	Ф0.30mm
Тор		2 Internal Layers		Bottom	
Copper Pattern	Thickness	Copper Pattern	Thickness	Copper Pattern	Thickness
Footprints and Traces	70µm	74.2mm x 74.2mm	35µm	74.2mm x 74.2mr	n 70µm

(Note 5) This thermal via connects with the copper pattern of all layers. The placement and dimensions obey a land pattern.

Electrical Characteristics

Unless otherwise specified, -40°C ≤ Ta ≤ +125°C, Vcc=13.5V, Io=0mA, VcτL=5.0V (With SW) The resistor of between ADJ and Vo =56.7kΩ, ADJ and GND =10kΩ (BD00C0AW)

Dorometer	Cumbal	Gua	Guaranteed Limit		Unit	Conditions
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Shutdown Current (With SW)	Isd	-	0	5	μA	Vctl=0V
Circuit Current	lb	-	0.5	2.5	mA	
ADJ Terminal Voltage (BD00C0AWFP/WHFP)	VADJ	0.742	0.750	0.758	V	Io=50mA, Ta=25°C
ADJ Terminal Voltage (BD00C0AW)	VADJ	0.727	0.750	0.773	V	Io=50mA
Output Voltage (BD33/50C0A(W9FP/(W)HFP)	Vo	Vo×0.99	Vo	Vo×1.01	V	Io=200mA, Ta=25°C
Output Voltage (BD33/50C0A(W))	Vo	Vo×0.97	Vo	Vo×1.03	V	Io=200mA
Output Voltage (BD80/90C0A(W)FP/(W)HFP)	Vo	Vo×0.99	Vo	Vo×1.01	V	Io=500mA, Ta=25°C
Output Voltage (BD80/90C0A(W))	Vo	Vo×0.97	Vo	Vo×1.03	V	Io=500mA
Dropout Voltage (BD00/50/80/90C0A(W))	ΔVd	-	0.3	0.5	V	Vcc=Vo×0.95,lo=500mA
Ripple Rejection (BD00/33/50C0A(W))	R.R.	45	55	-	dB	f=120Hz, Input Voltage Ripple =1Vms, Io=100mA
Ripple Rejection (BD80/90C0A(W))	R.R.	40	50	-	dB	f=120Hz, Input Voltage Ripple =1Vms, Io=100mA
Line Regulation	Reg.I	-	20	80	mV	Vo+1.0V ≤ V _{CC} ≤ 26.5V
Load Regulation	Reg.L	-	Vo ×0.010	Vo ×0.020	V	5mA ≤ lo ≤1A
CTL ON Mode Voltage (With SW)	VthH	2.0	_	_	V	ACTIVE MODE
CTL OFF Mode Voltage (With SW)	VthL	_	_	0.8	V	OFF MODE
CTL Bias Current (With SW)	ICTL	_	25	50	μΑ	

Reference Data

■BD00C0AW-C series(Vo=5.0V)

Unless otherwise specified, -40°C ≤ Ta ≤ +125°C, Vcc=13.5V, VcTL=5.0V, Io=0mA, Vo=5.0V

(The resistor of between ADJ and Vo =56.7kΩ, ADJ and GND =10kΩ)

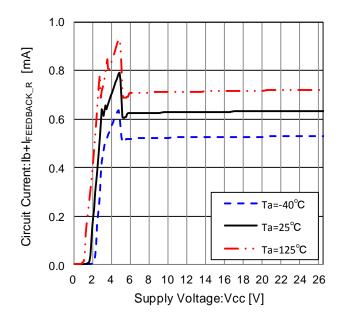


Figure 11. Circuit Current (IFEEDBACK_R^(Note 1) \approx 75 μ A) (Note 1) IFEEDBACK_R is the current flowing into external feedback resistance.

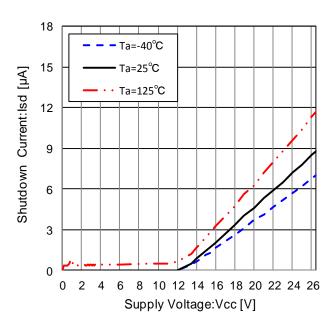


Figure 12. Shutdown Current (V_{CTL}=0V)

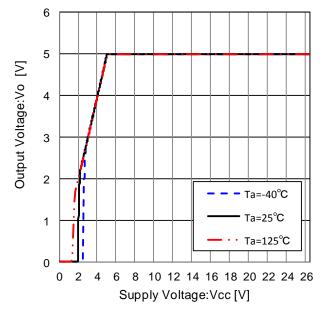


Figure 13. Line Regulation (Io=0mA)

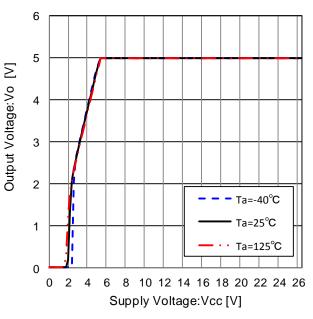


Figure 14. Line Regulation (Io=500mA)

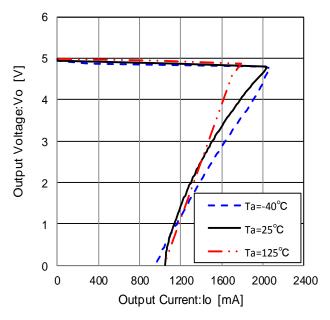


Figure 15. Load Regulation

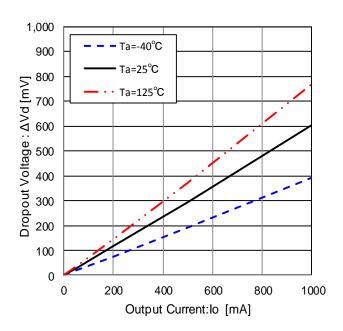


Figure 16. Dropout Voltage (Vcc=Vo×0.95=4.75V)

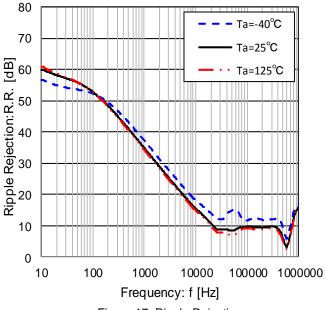
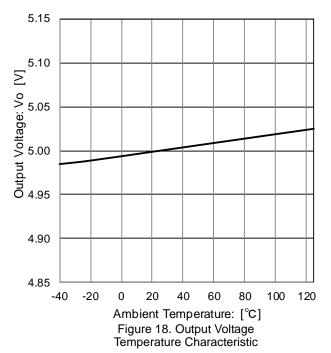


Figure 17. Ripple Rejection (lo=100mA)



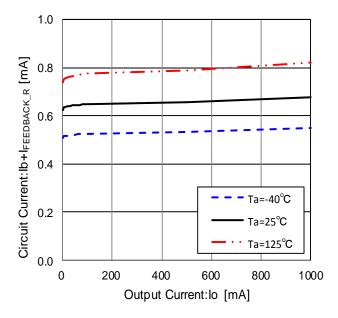


Figure 19. Circuit Current (0mA \leq Io \leq 1000mA, IFEEDBACK_R \approx 75 μ A)

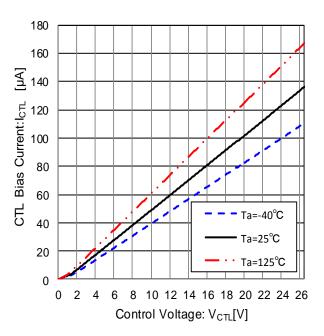


Figure 20. CTL Current vs CTL Voltage

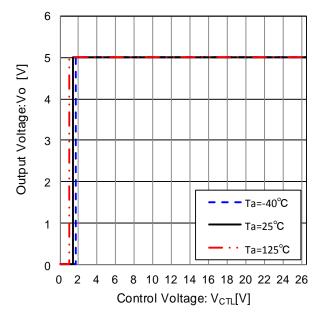


Figure 21. Output Voltage vs CTL Voltage

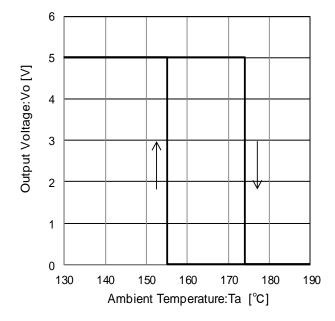
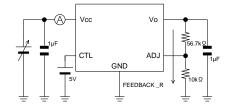
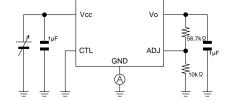


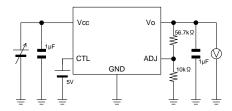
Figure 22. Thermal Shutdown Circuit Characteristic

Measurement setup for reference data

■BD00C0AW-C series (Vo=5.0V)



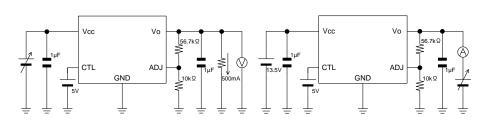


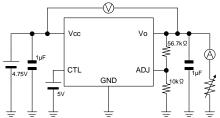


Measurement setup for Figure 11

Measurement setup for Figure 12

Measurement setup for Figure 13

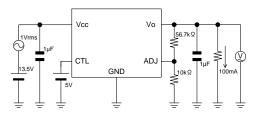


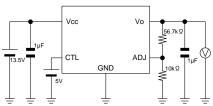


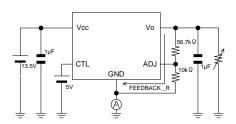
Measurement setup for Figure 14

Measurement setup for Figure 15

Measurement setup for Figure 16



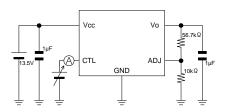


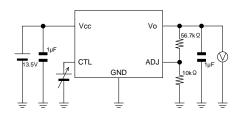


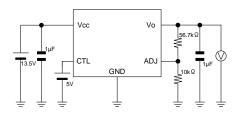
Measurement setup for Figure 17

Measurement setup for Figure 18

Measurement setup for Figure 19







Measurement setup for Figure 20

Measurement setup for Figure 21

Measurement setup for Figure 22

Reference Data

■BD33C0A-C/BD33C0AW-C series
Unless otherwise specified, -40°C ≤ Ta ≤ +125°C, Vcc=13.5V, V_{CTL}=5.0V (With SW), Io=0mA

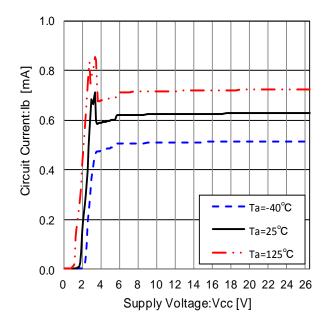


Figure 23. Circuit Current

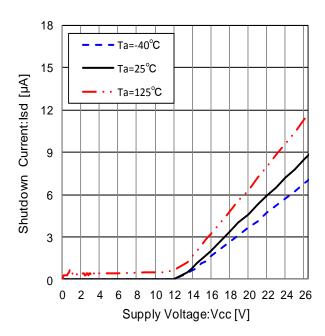


Figure 24. Shutdown Current (VcTL=0V)

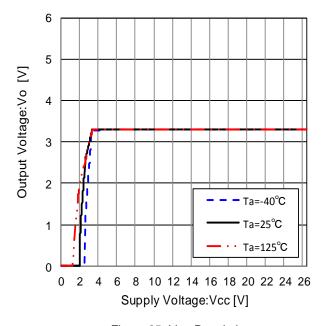
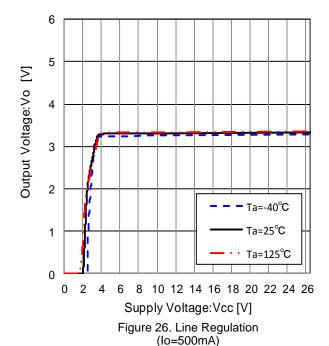


Figure 25. Line Regulation (Io=0mA)



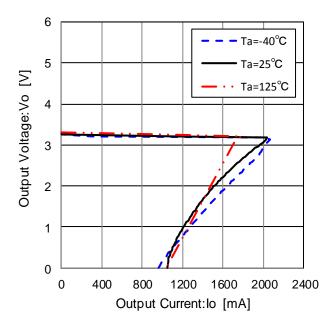


Figure 27. Load Regulation

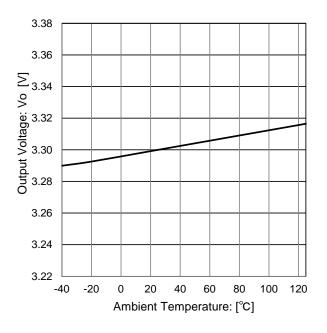


Figure 29. Output Voltage Temperature Characteristic

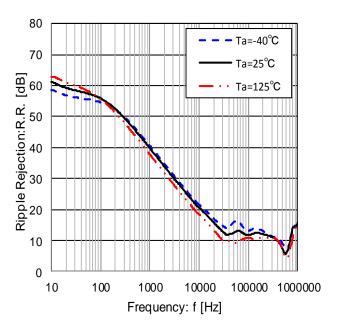


Figure 28. Ripple Rejection (lo=100mA)

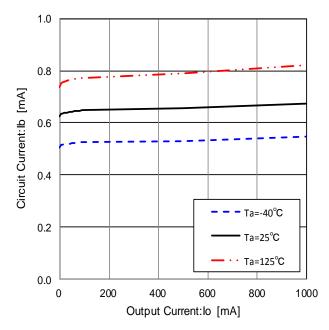


Figure 30. Circuit Current

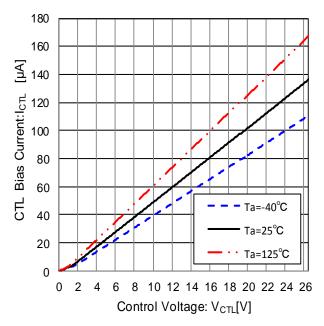


Figure 31. CTL Current vs CTL Voltage

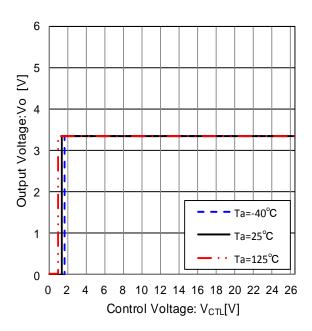


Figure 32. Output Voltage vs CTL Voltage

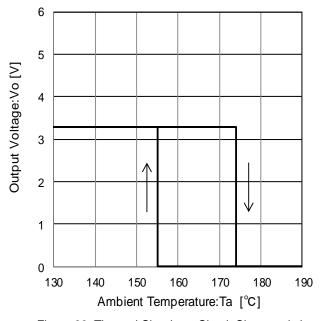


Figure 33. Thermal Shutdown Circuit Characteristic

Reference Data

■BD50C0A-C/BD50C0AW-C series
Unless otherwise specified, -40°C ≤ Ta ≤ +125°C, Vcc=13.5V, V_{CTL}=5.0V (With SW), Io=0mA

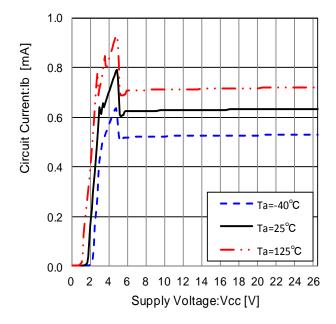


Figure 34. Circuit Current

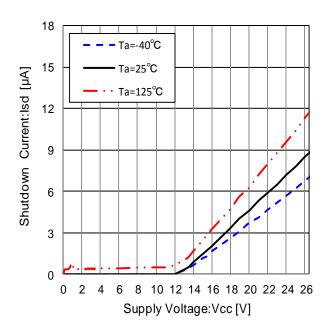


Figure 35. Shutdown Current (Vctl=0V)

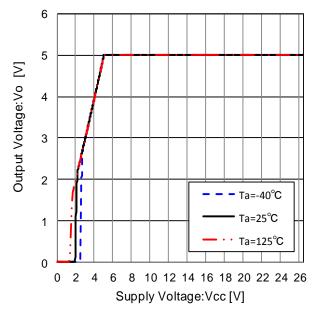


Figure 36. Line Regulation (Io=0mA)

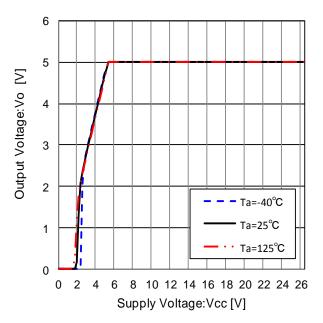


Figure 37. Line Regulation (Io=500mA)

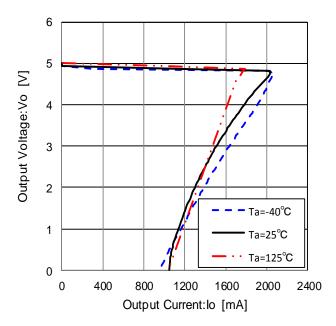


Figure 38. Load Regulation

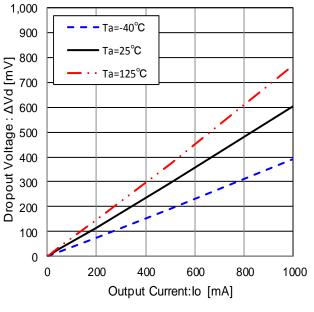


Figure 39. Dropout Voltage (Vcc=Vo×0.95V=4.75V)

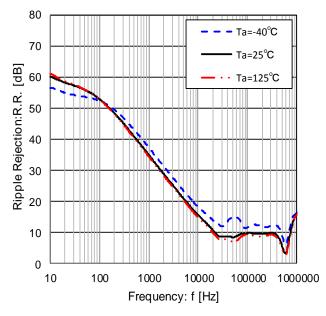


Figure 40. Ripple Rejection (Io=100mA)

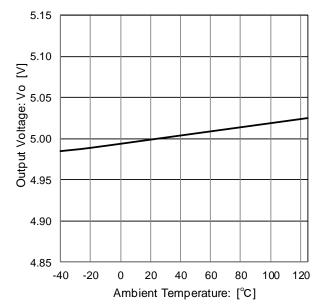


Figure 41. Output Voltage Temperature Characteristic

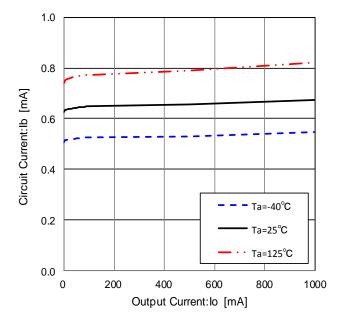


Figure 42. Circuit Current

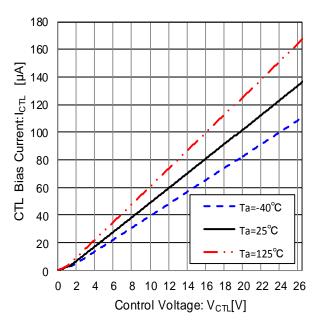


Figure 43. CTL Current vs CTL Voltage

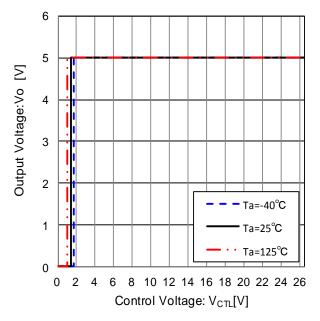


Figure 44. Output Voltage vs CTL Voltage

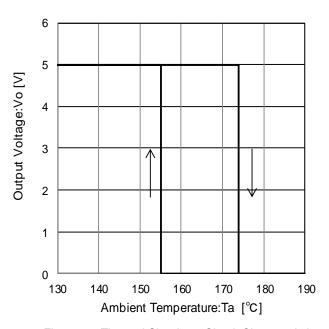


Figure 45. Thermal Shutdown Circuit Characteristic

Reference Data

■BD80C0A-C/ BD80C0AW-C series
Unless otherwise specified, -40°C ≤ Ta ≤ +125°C, Vcc=13.5V, VcTL=5.0V (With SW), Io=0mA

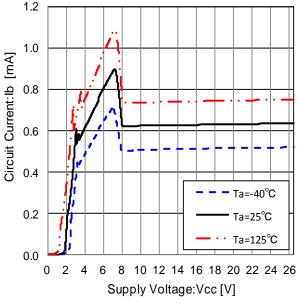


Figure 46. Circuit Current

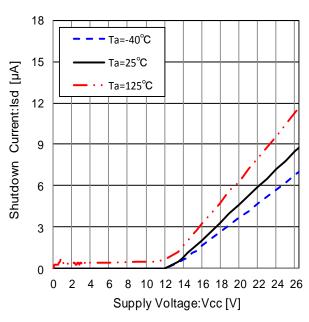


Figure 47. Shutdown Current (V_{CTL}=0V)

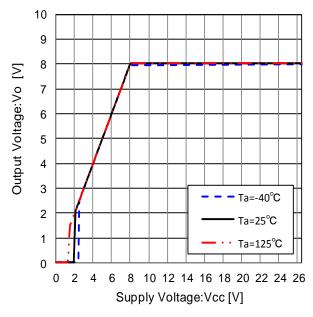


Figure 48. Line Regulation (Io=0mA)

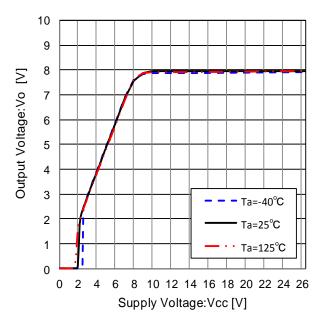


Figure 49. Line Regulation (Io=500mA)

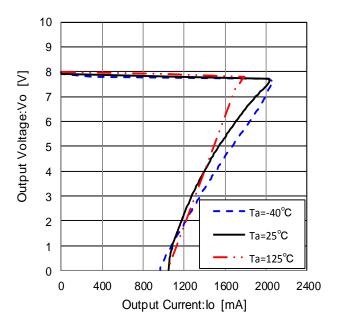


Figure 50. Load Regulation

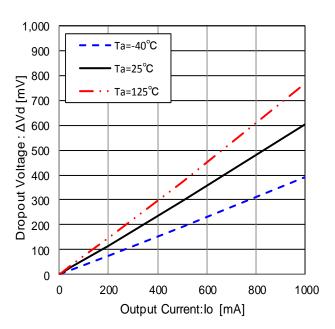


Figure 51. Dropout Voltage (Vcc=Vo×0.95V=7.6V)

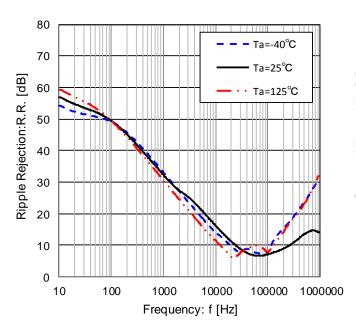


Figure 52. Ripple Rejection (Io=100mA)

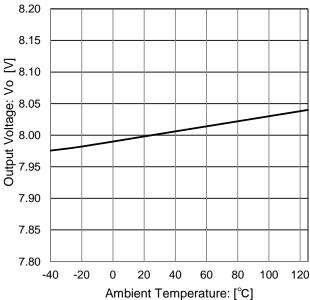


Figure 53. Output Voltage Temperature Characteristic

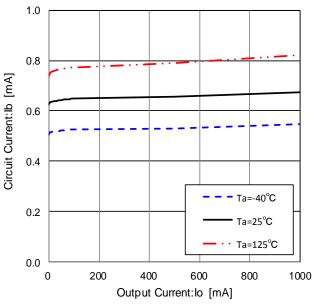


Figure 54. Circuit Current

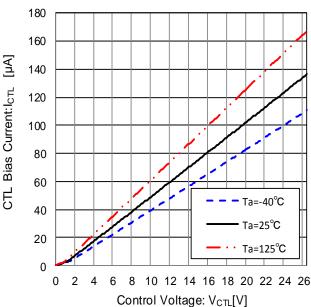


Figure 55. CTL Current vs CTL Voltage

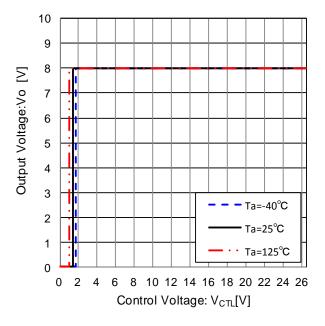


Figure 56. Output Voltage vs CTL Voltage

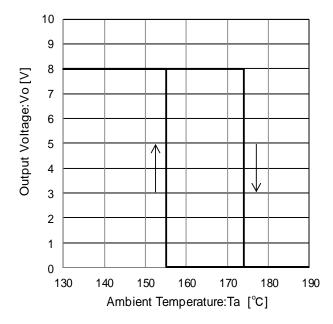


Figure 57. Thermal Shutdown Circuit Characteristic

Reference Data

■BD90C0A-C/BD90C0AW-C series
Unless otherwise specified, -40°C ≤Ta ≤ +125°C, Vcc=13.5V, VcTL=5.0V (With SW), Io=0mA

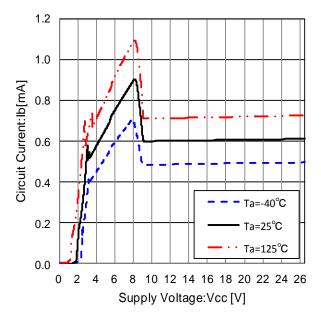


Figure 58. Circuit Current

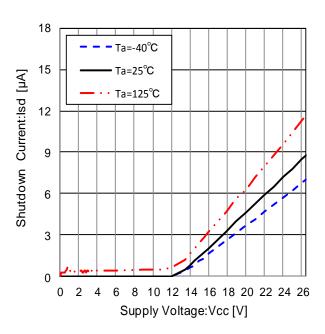


Figure 59. Shutdown Current (V_{CTL}=0V)

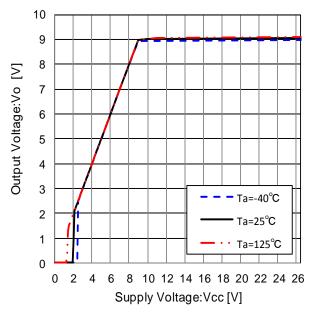


Figure 60. Line Regulation (Io=0mA)

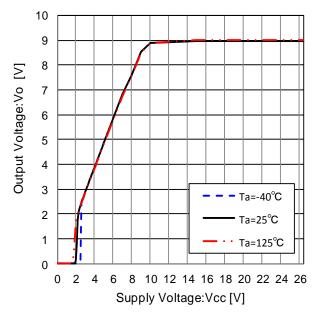


Figure 61. Line Regulation (Io=500mA)

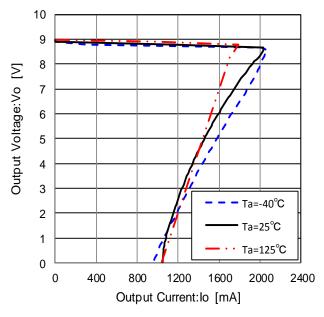


Figure 62. Load Regulation

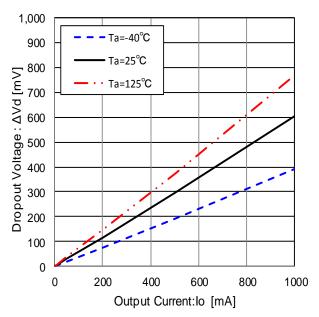


Figure 63. Dropout Voltage (Vcc=Vo×0.95V=8.55V)

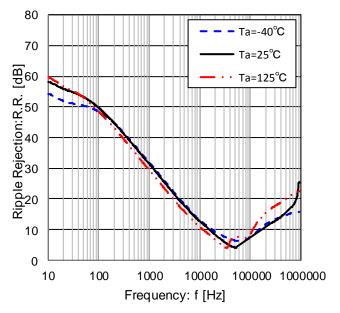


Figure 64. Ripple Rejection (Io =100mA)

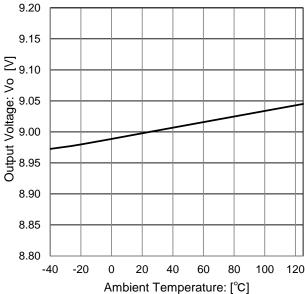


Figure 65. Output Voltage Temperature Characteristic

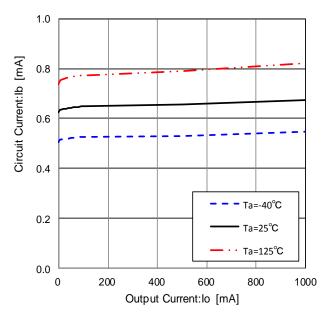


Figure 66. Circuit Current

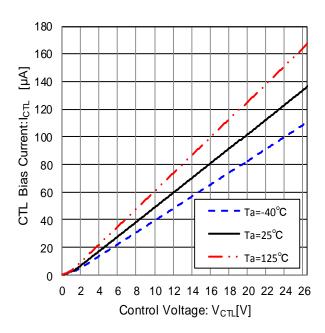


Figure 67. CTL Current vs CTL Voltage

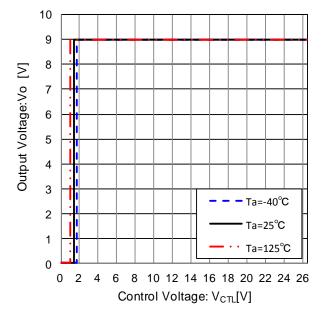


Figure 68. Output Voltage vs CTL Voltage

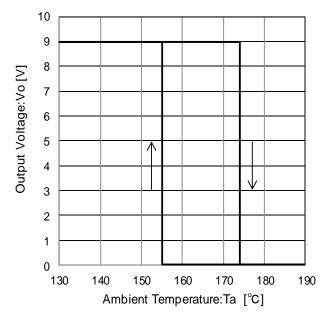
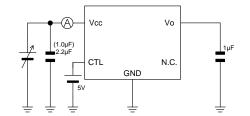


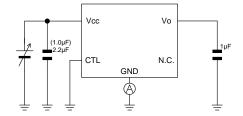
Figure 69. Thermal Shutdown Circuit Characteristic

Measurement setup for reference data

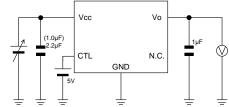
■BDxxC0AW-C series(Output Voltage Fixation Type)



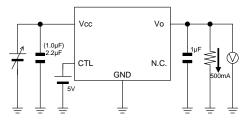
Measurement setup for Figure 23, 34, 46 and 58



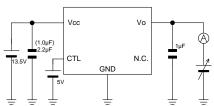
Measurement setup for Figure 24, 35, 47 and 59



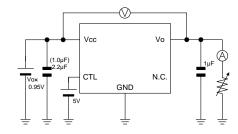
Measurement setup for Figure 25, 36, 48 and 60



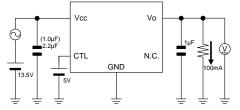
Measurement setup for Figure 26, 37, 49 and 61



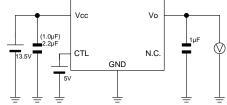
Measurement setup for Figure 27, 38, 50 and 62



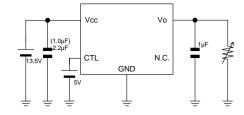
Measurement setup for Figure 39, 51 and 63



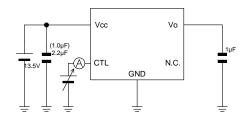
Measurement setup for Figure 28, 40, 52 and 64



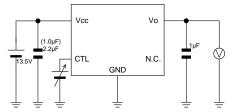
Measurement setup for Figure 29, 41, 53 and 65



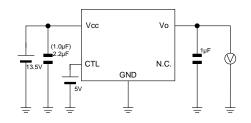
Measurement setup for Figure 30, 42, 54 and 66



Measurement setup for Figure 31, 43, 55 and 67



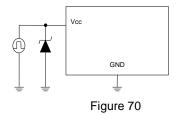
Measurement setup for Figure 32, 44, 56 and 68



Measurement setup for Figure 33, 45, 57 and 69

Application Examples

Applying positive surge to the Vcc pin
If the possibility exists that surges higher than 35.0V will be applied to the Vcc pin, a zenar diode should be placed
between the Vcc pin and GND pin as shown in the Figure below.



Applying negative surge to the Vcc pin
 If the possibility exists that negative surges lower than the GND are applied to the Vcc pin, a schottky diode should be place between the Vcc pin and GND pin as shown in the Figure below.

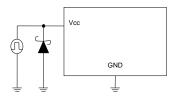


Figure 71

Implementing a protection diode
 If the possibility exists that a large inductive load is connected to the output pin resulting in back-EMF at time of startup and Shutdown, a protection diode should be placed as shown in the Figure below.

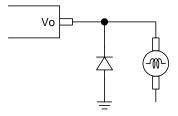


Figure 72

Thermal Design

■TO252-3

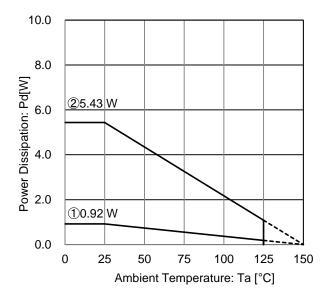


Figure 73. TO252-3 Package Data

IC mounted on ROHM standard board based on JEDEC.

1 : 1 - layer PCB

(Copper foil area on the reverse side of PCB: 0 mm x 0 mm)

Board material: FR4

Board size: 114.3 mm x 76.2 mm x 1.57 mmt

Mount condition: PCB and exposed pad are soldered.

Top copper foil: ROHM recommended footprint + wiring to measure, 2 oz. copper.

2 : 4 - layer PCB

(2 inner layers and Copper foil area on the reverse side of PCB:

74.2 mm x 74.2 mm) Board material: FR4

Board size: 114.3 mm x 76.2 mm x 1.60 mmt

Mount condition: PCB and exposed pad are soldered.

Top copper foil: ROHM recommended footprint + wiring to measure, 2 oz. copper. 2 inner layers copper foil area of PCB: 74.2 mm x 74.2 mm, 1 oz. copper. Copper foil area on the reverse side of PCB

Copper foil area on the reverse side of PC

: 74.2 mm x 74.2 mm, 2 oz. copper.

Condition(1): $\theta_{JA} = 81$ °C / W, Ψ_{JT} (top center) = 8 °C / W Condition(2): $\theta_{JA} = 21$ °C / W, Ψ_{JT} (top center) = 2 °C / W

■TO252-5

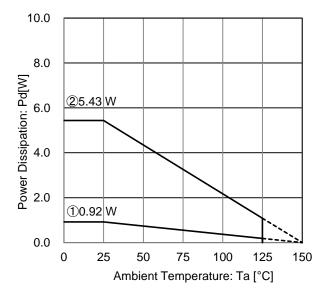


Figure 74. TO252-5 Package Data

IC mounted on ROHM standard board based on JEDEC.

① : 1 - layer PCB

(Copper foil area on the reverse side of PCB: 0 mm x 0 mm)

Board material: FR4

Board size: 114.3 mm x 76.2 mm x 1.57 mmt

Mount condition: PCB and exposed pad are soldered.

Top copper foil: ROHM recommended footprint + wiring to measure, 2 oz. copper.

2 : 4 - layer PCB

(2 inner layers and Copper foil area on the reverse side of PCB:

74.2 mm x 74.2 mm) Board material: FR4

Board size: 114.3 mm x 76.2 mm x 1.60 mmt

Mount condition: PCB and exposed pad are soldered.

Top copper foil: ROHM recommended footprint + wiring to measure, 2 oz. copper. 2 inner layers copper foil area of PCB: 74.2 mm x 74.2 mm, 1 oz. copper. Copper foil area on the reverse side of PCB

: 74.2 mm x 74.2 mm, 2 oz. copper.

Condition(1): θ_{JA} = 136 °C / W, Ψ_{JT} (top center) = 17 °C / W Condition(2): θ_{JA} = 23 °C / W, Ψ_{JT} (top center) = 3 °C / W

Thermal Design - continued

■HRP5

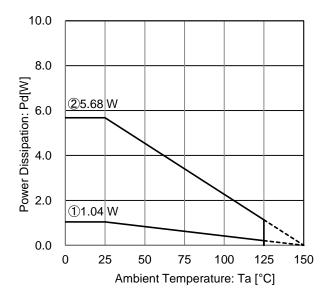


Figure 75. HRP5 Package Data

IC mounted on ROHM standard board based on JEDEC.

1 : 1 - layer PCB

(Copper foil area on the reverse side of PCB: 0 mm x 0 mm)

Board material: FR4

Board size: 114.3 mm x 76.2 mm x 1.57 mmt

Mount condition: PCB and exposed pad are soldered.

Top copper foil: ROHM recommended footprint + wiring to measure, 2 oz. copper.

② : 4 - layer PCB

(2 inner layers and Copper foil area on the reverse side of PCB:

74.2 mm x 74.2 mm) Board material: FR4

Board size: 114.3 mm x 76.2 mm x 1.60 mmt

Mount condition: PCB and exposed pad are soldered.

Top copper foil: ROHM recommended footprint + wiring to measure, 2 oz. copper. 2 inner layers copper foil area of PCB: 74.2 mm x 74.2 mm, 1 oz. copper.

Copper foil area on the reverse side of PCB

: 74.2 mm x 74.2 mm, 2 oz. copper.

Condition(1): $\theta_{JA} = 120 \, ^{\circ}\text{C} / \text{W}$, Ψ_{JT} (top center) = $8 \, ^{\circ}\text{C} / \text{W}$ Condition(2): $\theta_{JA} = 22 \, ^{\circ}\text{C} / \text{W}$, Ψ_{JT} (top center) = $3 \, ^{\circ}\text{C} / \text{W}$

Thermal Design - continued

■TO263-3(F)

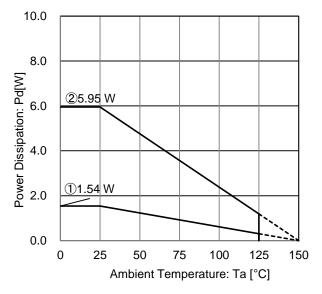


Figure 76. TO263-3 Package Data

IC mounted on ROHM standard board based on JEDEC.

1 : 1 - layer PCB

(Copper foil area on the reverse side of PCB: 0 mm x 0 mm)

Board material: FR4

Board size: 114.3 mm x 76.2 mm x 1.57 mmt

Mount condition: PCB and exposed pad are soldered.

Top copper foil: ROHM recommended footprint + wiring to measure, 2 oz. copper.

2 : 4 - layer PCB

(2 inner layers and Copper foil area on the reverse side of PCB:

74.2 mm x 74.2 mm) Board material: FR4

Board size: 114.3 mm x 76.2 mm x 1.60 mmt

Mount condition: PCB and exposed pad are soldered.

Top copper foil: ROHM recommended footprint + wiring to measure, 2 oz. copper. 2 inner layers copper foil area of PCB: 74.2 mm x 74.2 mm, 1 oz. copper.

Copper foil area on the reverse side of PCB

: 74.2 mm x 74.2 mm, 2 oz. copper.

Condition(1): $\theta_{JA} = 81$ °C / W, Ψ_{JT} (top center) = 8 °C / W Condition(2): $\theta_{JA} = 21$ °C / W, Ψ_{JT} (top center) = 2 °C / W

■TO263-5

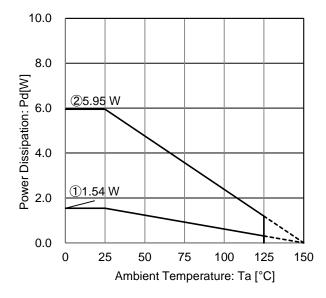


Figure 77. TO263-5 Package Data

IC mounted on ROHM standard board based on JEDEC.

1 : 1 - layer PCB

(Copper foil area on the reverse side of PCB: 0 mm x 0 mm)

Board material: FR4

Board size: 114.3 mm x 76.2 mm x 1.57 mmt

Mount condition: PCB and exposed pad are soldered.

Top copper foil: ROHM recommended footprint + wiring to measure, 2 oz. copper.

2 : 4 - layer PCB

(2 inner layers and Copper foil area on the reverse side of PCB:

74.2 mm x 74.2 mm) Board material: FR4

Board size: 114.3 mm x 76.2 mm x 1.60 mmt

Mount condition: PCB and exposed pad are soldered.

Top copper foil: ROHM recommended footprint + wiring to measure, 2 oz. copper. 2 inner layers copper foil area of PCB: 74.2 mm x 74.2 mm, 1 oz. copper. Copper foil area on the reverse side of PCB

: 74.2 mm x 74.2 mm, 2 oz. copper.

Condition(1): $\theta_{JA} = 81$ °C / W, Ψ_{JT} (top center) = 8 °C / W Condition(2): $\theta_{JA} = 21$ °C / W, Ψ_{JT} (top center) = 2 °C / W

When operating at temperature more than Ta=25°C, please refer to the power dissipation characteristic curve shown in Figure 73 to 77.

The IC characteristics are closely related to the temperature at which the IC is used, so it is necessary to operate the IC at temperatures less than the maximum junction temperature Timax.

Figure. 73 to 77 shows the acceptable power dissipation characteristic curves of the TO252-3/5, HRP5 and TO263-3(F)/5 packages. Even when the ambient temperature (Ta) is at normal temperature (25°C), the chip junction temperature (Tj) may be quite high so please operate the IC at temperatures less than the acceptable power dissipation.

The calculation method for power consumption Pc(W) is as follows

Pc=(Vcc-Vo)×lo+Vcc×lb Acceptable loss Pd≥Pc

Solving this for load current lo in order to operate within the acceptable loss

Vcc : Input voltage
Vo : Output voltage
Io : Load current
Ib : Circuit current

Io
$$\leq \frac{Pd-Vcc \times Ib}{Vcc-Vo}$$
 (Please refer to 19, 30, 42, 54 and 66 about Ib.)

It is then possible to find the maximum load current lomax with respect to the applied voltage Vcc at the time of thermal design.

Calculation Example) When TO252-3 / TO252-5, 4-layer PCB, Ta=85°C, Vcc=13.5V, Vo=5.0V

$$lo \le \frac{2.824 - 13.5 \times lb}{8.5}$$
 Figure 73, 74 @ θ ja=23°C /W \rightarrow -43.5mW/°C 25°C = 5.43W \rightarrow 85°C =2.824W

Calculation Example) When HRP5, 4-layer PCB, Ta=85°C, Vcc=13.5V, Vo=5.0V

$$lo \leq \frac{2.954 - 13.5 \times lb}{8.5}$$
 Figure 75 @6ja=22°C /W \rightarrow -45.5mW/°C 25°C =5.68W \rightarrow 85°C =2.954W

Calculation Example) When TO263-3(F) / TO263-5, 4-layer PCB, Ta=85°C, Vcc=13.5V, Vo=5.0V

$$lo \le \frac{3.094 - 13.5 \times lb}{8.5}$$
 Figure 76, 77 @0ja=21°C /W \rightarrow -47.6mW/°C 25°C =5.95W \rightarrow 85°C =3.094W

Please refer to the above information and keep thermal designs within the scope of acceptable loss for all operating temperature ranges.

I/O equivalence circuit

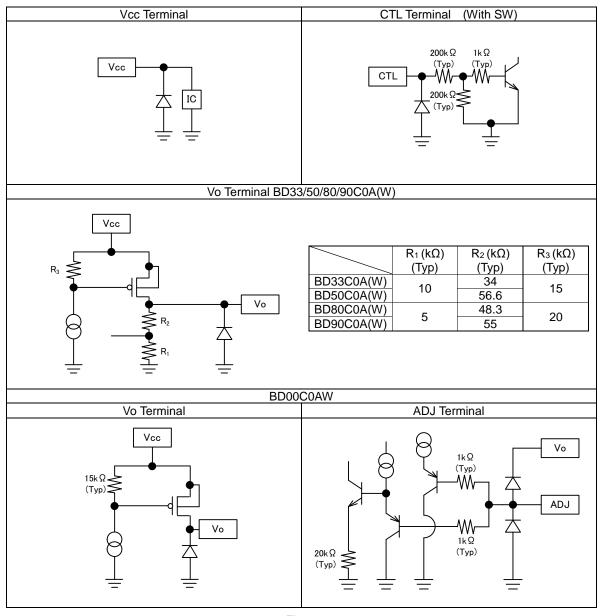
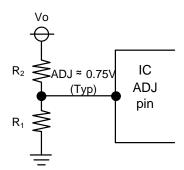


Figure 78

Output Voltage Configuration Method (BD00C0AW)

Please connect resistors R₁ and R₂ (which determines the output voltage) as shown in Figure 79.

Please be aware that the offset due to the current that flows from the $\bar{A}DJ$ terminal becomes large when resistor values are large. Due to this, resistance ranging from $5k\Omega$ to $10k\Omega$ is highly recommended for R_1 .



Vo
$$\approx$$
 ADJ \times (R₁+R₂) / R₁

The circuit current dependents on the resistance value of R_1 and R_2 . Please determine the constant considering the actual application.

Figure 79

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. Power dissipation in the Thermal Design is the value when the IC is mounted on a 114.3mm x 76.2mm x 1.57mm/1.6mm glass epoxy board. And in case this exceeds, take the measures like enlarge the size of board; make copper foil area for heat dissipation big; and do not exceed the power dissipation.

6. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

7. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

8. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

9. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

Operational Notes - continued

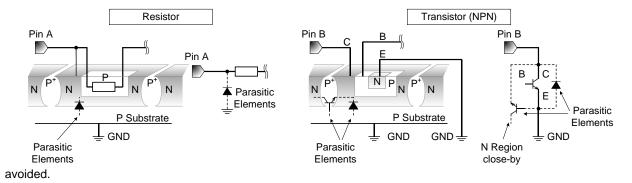
10. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.

When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be



11. Ceramic Capacitor

When using a ceramic capacitor, determine the dielectric constant considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

12. Thermal Shutdown Circuit(TSD)

This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's power dissipation rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF all output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.

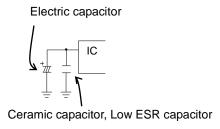
Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

13. Over Current Protection Circuit (OCP)

This IC incorporates an integrated overcurrent protection circuit that is activated when the load is shorted. This protection circuit is effective in preventing damage due to sudden and unexpected incidents. However, the IC should not be used in applications characterized by continuous operation or transitioning of the protection circuit.

14. Vcc Pin

Insert a capacitor (Vo \geq 5.0V:capacitor \geq 1µF, 1.0 \leq Vo < 5.0V:capacitor \geq 2.2µF) between the Vcc and GND pins. Choose the capacitance according to the line between the power smoothing circuit and the Vcc pin. Selection of the capacitance also depends on the application. Verify the application and allow for sufficient margins in the design. We recommend using a capacitor with excellent voltage and temperature characteristics.



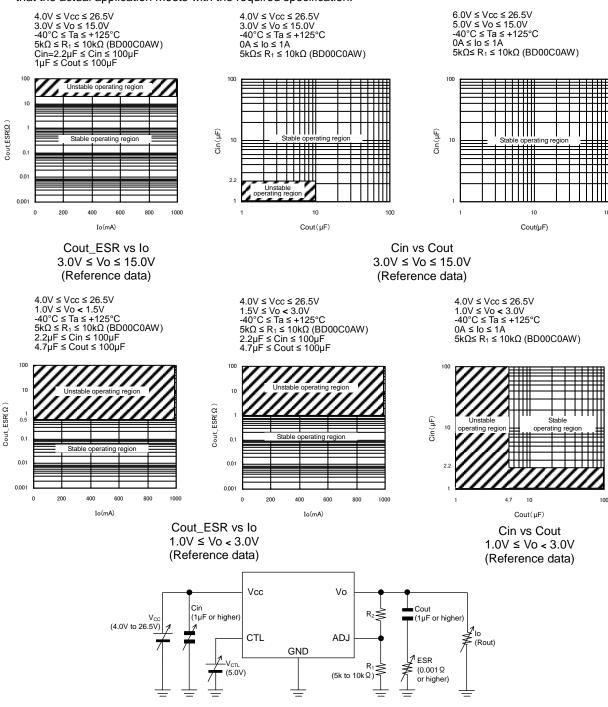
Operational Notes - continued

15. Output Pin

In order to prevent oscillation, a capacitor needs to be placed between the output pin and GND pin. We recommend a capacitor with a capacitance of more than $1\mu F(3.0V \le Vo \le 15.0V)$. Electrolytic, tantalum and ceramic capacitors can be used. We recommend a capacitor with a capacitance of more than $4.7\mu F(1.0V \le Vo < 3.0V)$. Ceramic capacitors can be used. If electrolytic and tantalum capacitors of more than $4.7\mu F$ with a high ESR characteristic are used($1.0V \le Vo < 3.0V$), 10 μF ceramic capacitor needs to be connected in parallel. When selecting the capacitor ensure that the capacitance of more than $1\mu F(3.0V \le Vo \le 15.0V)$ or more than $4.7\mu F(1.0V \le Vo < 3.0V)$ is maintained at the intended applied voltage and temperature range. Due to changes in temperature, the capacitance can fluctuate possibly resulting in oscillation. For selection of the capacitor refer to the Cout_ESR vs lo data. The stable operation range given in the reference data is based on the standalone IC and resistive load. For actual applications the stable operating range is influenced by the PCB impedance, input supply impedance and load impedance. Therefore verification of the final operating environment is needed.

When selecting a ceramic type capacitor, we recommend using X5R, X7R or better with excellent temperature and DC-biasing characteristics and high voltage tolerance.

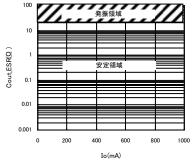
Also, in case of rapidly changing input voltage and load current, select the capacitance in accordance with verifying that the actual application meets with the required specification.



Operation Note 15 Measurement circuit (BD00C0AW)

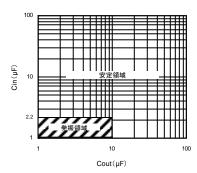
Operational Notes - continued

 $4.0V \leq Vcc \leq 26.5V$ $1.0V \leq Vo < 3.0V$ (Cout and Ceramic capacitor $10\mu F$ is connected in parallel.) $-40^{\circ}C \leq Ta \leq +125^{\circ}C$ $5k\Omega \leq R_1 \leq 10k\Omega$ (BD00C0AW) $2.2\mu F \leq Cin \leq 100\mu F$ $1\mu F \leq Cout \leq 100\mu F$

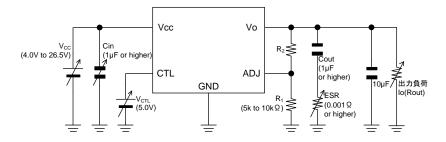


Cout_ESR vs Io 1.0V ≤ Vo < 3.0V Cout and Ceramic capacitor 10µF is connected in parallel. (Reference data)

 $4.0V \le Vcc \le 26.5V$ $1.0V \le Vo < 3.0V$ (Cout and Ceramic capacitor $10\mu F$ is connected in parallel.) $-40^{\circ}C \le Ta \le +125^{\circ}C$ $0A \le Io \le 1A$ $5k\Omega \le R_1 \le 10k\Omega$ (BD00C0AW)



Cin vs Cout
1.0V ≤ Vo < 3.0V
Cout and Ceramic capacitor 10µF is
connected in parallel.
(Reference data)



Operation Note 15 Measurement circuit (BD00C0AW)

16. CTL Pin

Do not set the voltage level on the IC's enable pin in between VthH and VthL. Do not leave it floating or unconnected, otherwise, the output voltage would be unstable.

17. Rapid variation in Vcc Voltage and load Current CTL Pin

In case of a rapidly changing input voltage, transients in the output voltage might occur due to the use of a MOSFET as output transistor. Although the actual application might be the cause of the transients, the IC input voltage, output current and temperature are also possible causes. In case problems arise within the actual operating range, use countermeasures such as adjusting the output capacitance.

18. Minute variation in output voltage

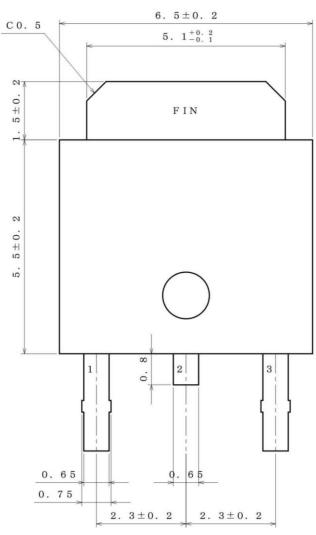
In case of using an application susceptible to minute changes to the output voltage due to noise, changes in input and load current, etc., use countermeasures such as implementing filters.

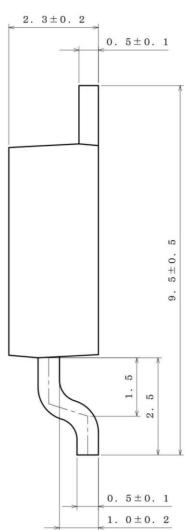
19. In some applications, the Vcc and pin potential might be reversed, possibly resulting in circuit internal damage or damage to the elements. For example, while the external capacitor is charged, the Vcc shorts to the GND. Use a capacitor with a capacitance with less than 1000µF. We also recommend using reverse polarity diodes in series or a bypass between all pins and the Vcc pin.

Physical Dimension, Tape and Reel Information

Package Name

TO252-3



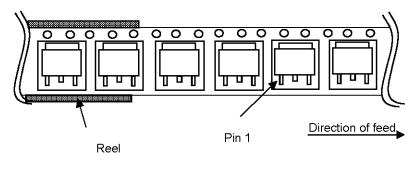


(UNITS; mm) PKG: TO252-3

Drawing No. EX535-5001-1

< Tape and Reel Information >

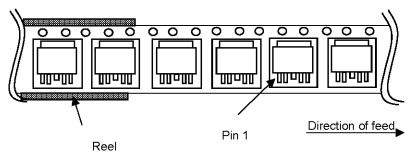
Таре	Embossed carrier tape			
Quantity	2000pcs			
Direction of feed	E2 The direction is the 1pin of product is at the lower left when you hold reel on the left hand and you pull out the tape on the right hand			



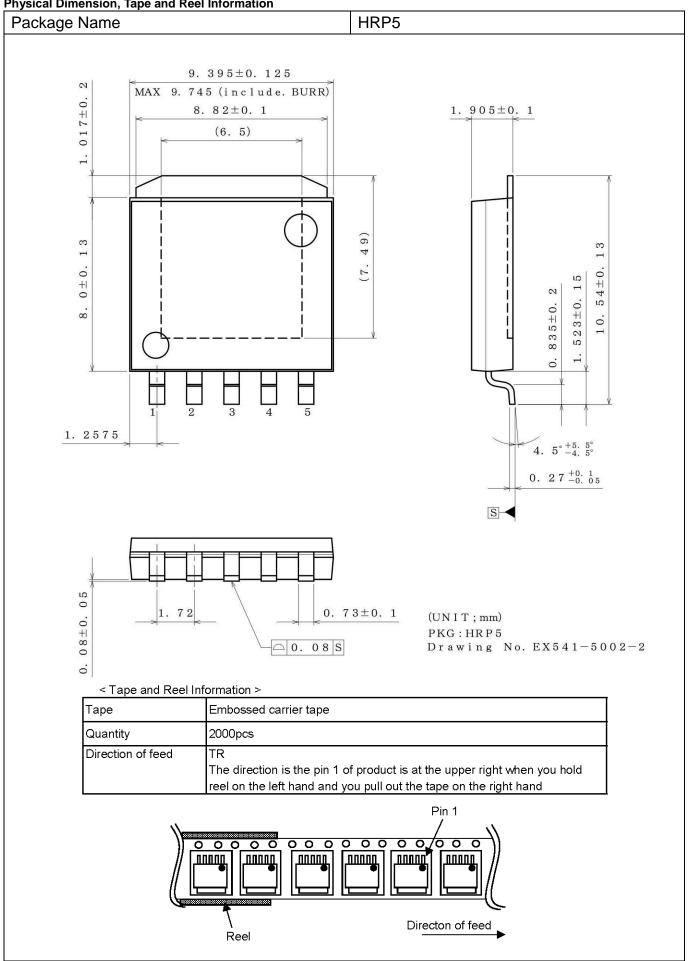
BDxxC0A-C series BDxxC0AW-C series **Datasheet Physical Dimension, Tape and Reel Information** Package Name TO252-5 6. 5 ± 0.2 2.3 ± 0.2 5. $1^{+0.2}_{-0.1}$ CO. 5 0. 5 ± 0.1 5 ± 0 . FIN 5 ± 0 9. 0 2 2 12 0.5 ± 0.1 0.5 1. 27 1. 0 ± 0 . 2 (UNIT: mm) PKG: TO252-5 Drawing No. EX536-5001-1

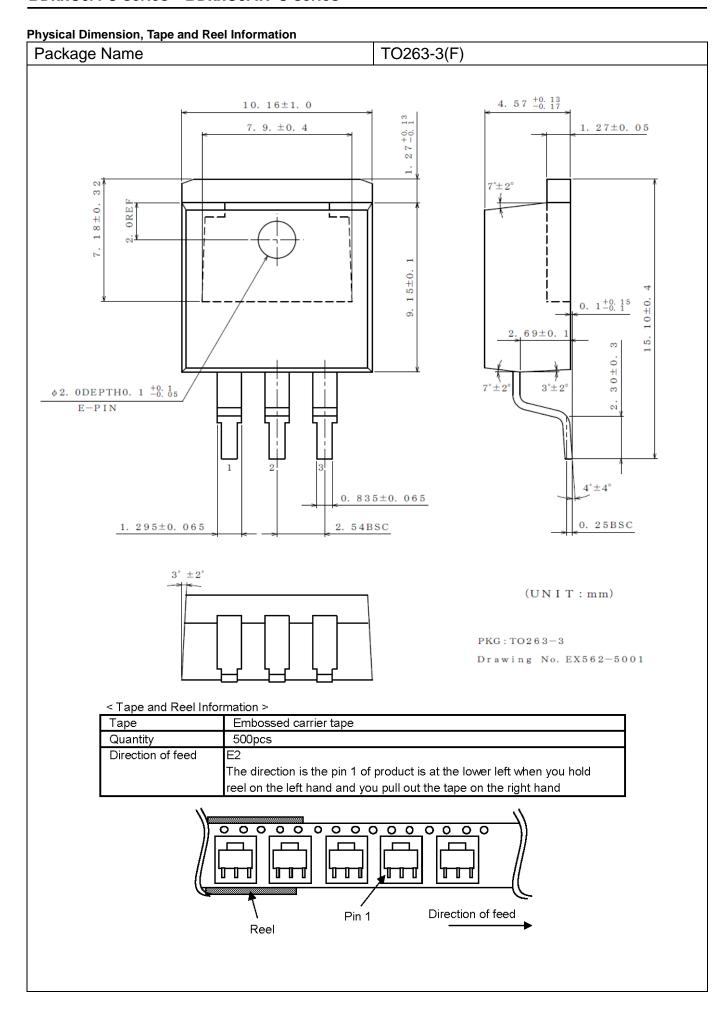
< Tape and Reel Information >

Таре	Embossed carrier tape
Quantity	2000pcs
Direction of feed	E2 The direction is the 1pin of product is at the lower left when you hold reel on the left hand and you pull out the tape on the right hand

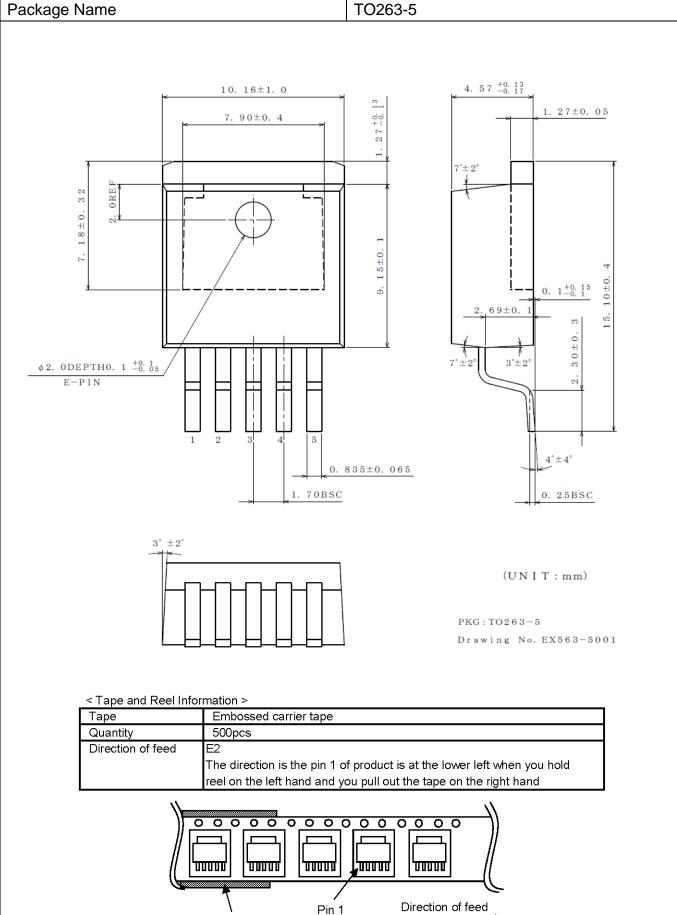


Physical Dimension, Tape and Reel Information





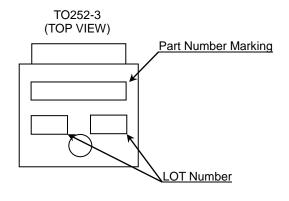
Physical Dimension, Tape and Reel Information Package Name



Reel

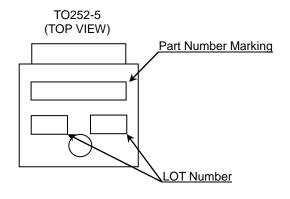
Marking Diagrams (TOP VIEW)

TO252-3



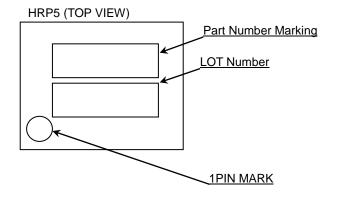
Output Voltage(V)	Part Number Marking
3.3	33C0AC
5.0	50C0AC
8.0	80C0AC
9.0	90C0AC

TO252-5



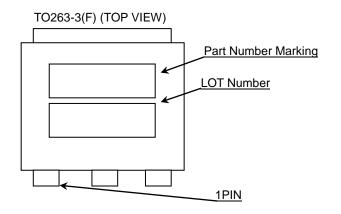
Output Voltage(V)	Part Number Marking
Variable	00C0AWC
3.3	33C0AWC
5.0	50C0AWC
8.0	80C0AWC
9.0	90C0AWC

HRP5



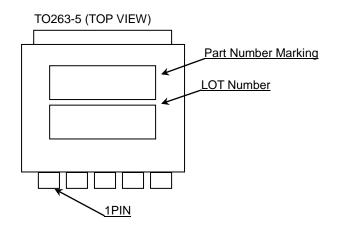
Output Voltage(V)	Output Control Pin	Part Number Marking
Variable	With SW	00C0AWHFPC
3.3	With SW	33C0AWHFPC
3.3	Without SW	33C0AHFPC
5.0	With SW	50C0AWHFPC
5.0	Without SW	50C0AHFPC
8.0	With SW	80C0AWHFPC
8.0	Without SW	80C0AHFPC
9.0	With SW	90C0AWHFPC
3.0	Without SW	90C0AHFPC

TO263-3(F)



Output Voltage(V)	Part Number Marking	
3.3	33C0AC	
5.0	50C0AC	
8.0	80C0AC	
9.0	90C0AC	

TO263-5



Output Voltage(V)	Part Number Marking
Variable	00C0AWC
3.3	33C0AWC
5.0	50C0AWC
8.0	80C0AWC
9.0	90C0AWC

Revision History

Date	Revision	Changes
16.Nov.2012	001	New Release
07.Mar.2013	002	The condition of output pin is changed on Operational Note 11. The mention of "Status of this document" is removed.
2.Sep.2013	003	 Error in writing were corrected New release TO263-3F, TO263-5F, packages. Thermal Resistance and Power Dissipation are changed to be compliant with JEDEC standard. All characters were conformed to the Chicago manual. The sign in the annotation part was changed from "%n" into "(Note n)." NOTE under the absolute maximum rating of P.2 was deleted because it had overlapped with P.1. Sentences of "Power consumption Pc of IC when short-circuited" that exists in P.30 are deleted. "Operational Notes" were updated.
		Page. 31 Error in writing were corrected
27.Jan.2017	005	 TO263-3 and TO263-5 were added. The description method of thermal Resistance was changed to unify. AEC-Q100 (Note1:Grade1) was appended. Drop voltage figure was corrected. (P.12, 25) Figure 78 I/O equivalent was corrected. (P.31) Error in direction of feed was corrected. (P.39, 40)

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(Note1) Medical Equipment Classification of the Specific Applications

JAPAN USA		EU	CHINA
CLASSⅢ	CLASSⅢ	CLASS II b	ОГУООШ
CLASSIV		CLASSⅢ	CLASSⅢ

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 - [h] Use of the Products in places subject to dew condensation
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- 8. Confirm that operation temperature is within the specified range described in the product specification.
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CTR BD33C0AWHFP-CTR BD80C0AHFP-CTR BD80C0AWHFP-CTR